

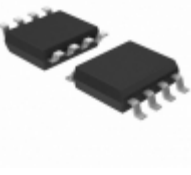


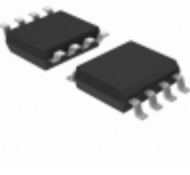



	<h2>RSS090P03TB</h2>
	<p>Hersteller-Teilenummer: RSS090P03TB</p> <p>Hersteller / Marke: LAPIS Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 30V 9A 8-SOIC</p> <p>Datenblätter:  RSS090P03TB.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 60820 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	RSS090P03TB
Hersteller	LAPIS Semiconductor
Beschreibung	MOSFET P-CH 30V 9A 8-SOIC
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	60820 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	150 °C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOP
Verlustleistung (max)	2W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	9A (Ta)
Rds On (Max) @ Id, Vgs	14 mOhm @ 9A, 10V
VGS (th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	39nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	4000pF @ 10V
Verpackung	Cut Tape (CT)






































RSS090P03TB ist neu im Original, Suche RSS090P03TB Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RSS090P03TB LAPIS Semiconductor mit Garantie und Vertrauen. Anfrage RSS090P03TB: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>RSS095N05FU6TB LAPIS Semiconductor MOSFET N-CH 45V 9.5A 8-SOIC</p>	 <p>RSS090P03.TB ROHM RSS090P03.TB ROHM</p>	 <p>RSS095N05TB ROHM RSS095N05TB ROHM</p>	 <p>RSS090P03FU6TB LAPIS Semiconductor MOSFET P-CH 30V 9A 8SOIC</p>
 <p>RSS090P03FU7TB LAPIS Semiconductor MOSFET P-CH 30V 9A 8SOIC</p>	 <p>RSS090P03TB1 ROHM ROHM SOP8</p>	 <p>RSS090P03FU7 TB ROHM RSS090P03FU7 TB ROHM</p>	 <p>RSS0E561MCN1GS Nichicon CAP ALUM POLY 560UF 20% 2.5V SMD</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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